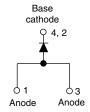


### Vishay Semiconductors

## Schottky Rectifier, 5.5 A





	V /	TO-252	
D-PF	<b>1</b>	10-202	ZAAI

PRODUCT SUMMARY				
Package	D-PAK (TO-252AA)			
I <sub>F(AV)</sub>	5.5 A			
V <sub>R</sub>	40 V			
V <sub>F</sub> at I <sub>F</sub>	See Electrical table			
I <sub>RM</sub>	40 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
Diode variation	Single die			
E <sub>AS</sub>	9 mJ			

#### **FEATURES**

- Popular D-PAK outline
- Small foot print, surface mountable



- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- $\bullet$  Meets MSL level 1, per J-STD-020, LF maximum peak of 260  $^{\circ}\text{C}$

#### **DESCRIPTION**

The VS-50WQ04FNPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I <sub>F(AV)</sub>	Rectangular waveform	5.5	А			
$V_{RRM}$		40	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 µs sine	340	Α			
V <sub>F</sub>	5 Apk, T <sub>J</sub> = 125 °C	0.44	V			
T <sub>J</sub>	Range	- 40 to 150	°C			

VOLTAGE RATINGS					
PARAMETER SYMBOL VS-50WQ04FNPbF UNITS					
Maximum DC reverse voltage	$V_{R}$	40	V		
Maximum working peak reverse voltage	$V_{RWM}$	40	V		

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS				
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 135 °C, I	rectangular waveform	5.5			
Maximum peak one cycle non-repetitive surge current	1	5 µs sine or 3 µs rect. pulse Following any rated load condition and with rated	550	Α			
See fig. 7	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	90			
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.5 A, L = 8 mH		9	mJ		
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s  Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical			А		

# VS-50WQ04FNPbF

# Vishay Semiconductors

### Schottky Rectifier, 5.5 A



Document Number: 94233

Revision: 14-Jan-11

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS			
		5 A	T <sub>.1</sub> = 25 °C	0.51	V		
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	10 A	11=23 0	0.63			
See fig. 1	VFM ('')	5 A	T 405 00	0.44			
		10 A	T <sub>J</sub> = 125 °C	0.59			
Maximum reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	3	mA		
See fig. 2		T <sub>J</sub> = 125 °C	v <sub>R</sub> = nateu v <sub>R</sub>	40			
Thereshold voltage	V <sub>F(TO)</sub>	T <sub>J</sub> =T <sub>J</sub> maximum		0.27	V		
Forward slope resistance	r <sub>t</sub>			26.77	mΩ		
Typical junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal range 100 kHz to 1 MHz), 25 °C 40		405	pF		
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm fi	rom package body	5.0	nH		

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		- 40 to 150	°C			
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation See fig. 4	3.0	°C/W			
Approximate weight			0.3	g			
Approximate weight			0.01	oz.			
Marking device		Case style D-PAK (similar to TO-252AA)	50WQ0	04FN			

#### Note



### Schottky Rectifier, 5.5 A

## Vishay Semiconductors

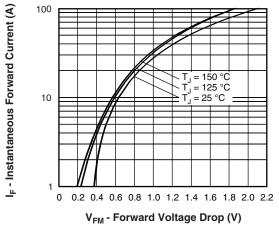


Fig. 1 - Maximum Forward Voltage Drop Characteristics

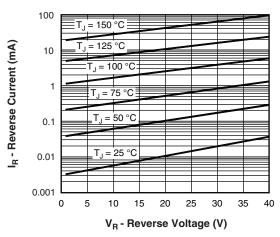


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

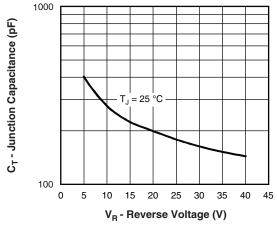


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

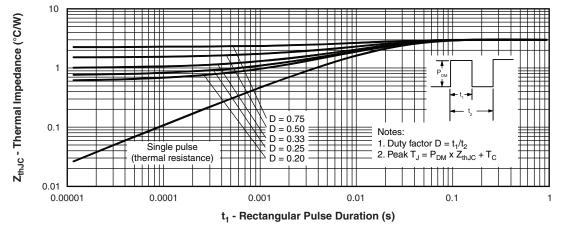


Fig. 4 - Maximum Thermal Impedance  $Z_{\text{thJC}}$  Characteristics

## Vishay Semiconductors

### Schottky Rectifier, 5.5 A



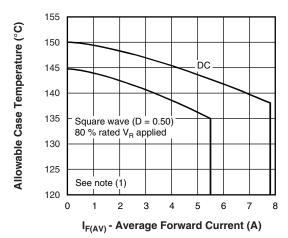


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

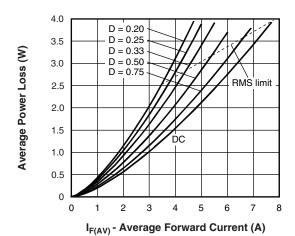


Fig. 6 - Forward Power Loss Characteristics

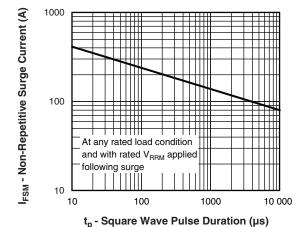


Fig. 7 - Maximum Non-Repetitive Surge Current

#### Note

(1) Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$ ;  $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1} = 80 \%$  rated  $V_R$ 

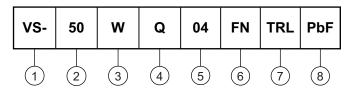


### Schottky Rectifier, 5.5 A

### Vishay Semiconductors

#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

Current rating (5.5 A)

3 - Package identifier:

W = D-PAK

4 - Schottky "Q" series

5 - Voltage rating (04 = 40 V)

6 - FN = TO-252AA (D-PAK)

7 - • None = Tube (50 pieces)

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

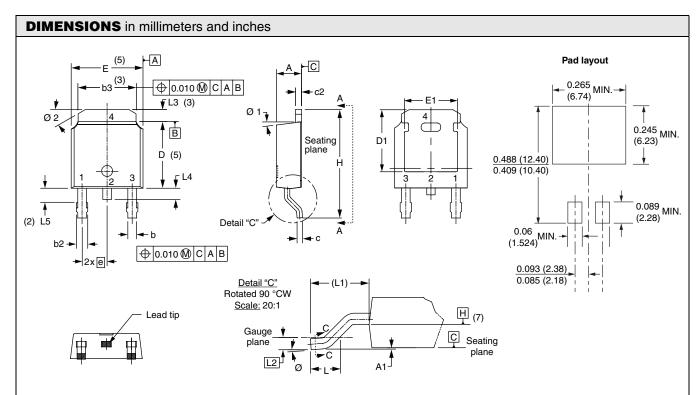
8 - PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95016			
Part marking information	www.vishay.com/doc?95059			
Packaging information	www.vishay.com/doc?95033			



## Vishay High Power Products

## **D-PAK (TO-252AA)**



SYMBOL	MILLIM	ETERS	INC	INCHES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	2.18	2.39	0.086	0.094	
A1	-	0.13	-	0.005	
b	0.64	0.89	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	3
С	0.46	0.61	0.018	0.024	
c2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	5
D1	5.21	-	0.205	-	3
Е	6.35	6.73	0.250	0.265	5
E1	4.32	-	0.170	-	3

SYMBOL	MILLIM	MILLIMETERS		INCHES	
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29	BSC	0.090	BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74	2.74 BSC		0.108 REF.	
L2	0.51	0.51 BSC		0.020 BSC	
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	
Ø2	25°	35°	25°	35°	

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- $^{(7)}$  Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA





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